VT1080S, VFT1080S, VBT1080S, VIT1080S

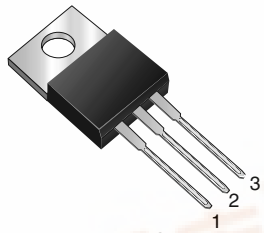
Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier

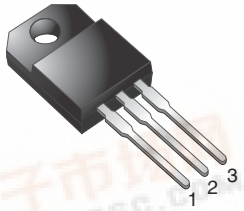
Ultra Low V_F = 0.52 V at I_F = 5 A

TMBS®

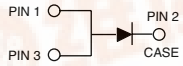
TO-220AB



ITO-220AB



VT1080S



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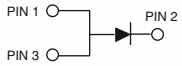

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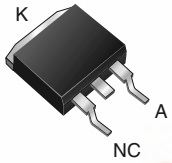
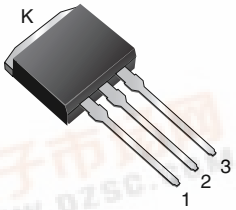
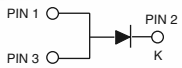


TO-262AA



VBT1080S

VIT1080S



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb e3 RoHS COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA
Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	10 A
V_{RRM}	80 V
I_{FSM}	100 A
V_F at I_F = 10 A	0.60 V
T_J max.	150 °C

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	VT1080S	VFT1080S	VBT1080S	VIT1080S	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	80				V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	10				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	100				A
Non-repetitive avalanche energy at T_J = 25 °C, L = 60 mH	E_{AS}	110				mJ
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T_J = 38 °C ± 2 °C	I_{RRM}	1.0				A
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V_{AC}	1500				V
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150				°C

VT1080S, VFT1080S, VBT1080S, VIT1080S

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I_R = 10 mA	T_A = 25 °C	V_{BR}	80 (minimum)	-	V
Instantaneous forward voltage	I_F = 5 A	T_A = 25 °C	V_F (1)	0.57	-	V
	I_F = 10 A			0.67	0.81	
	I_F = 5 A	T_A = 125 °C		0.52	-	
	I_F = 10 A			0.60	0.70	
Reverse current	V_R = 80 V	T_A = 25 °C	I_R (2)	20	600	µA
		T_A = 125 °C		10	20	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VT1080S	VFT1080S	VBT1080S	VIT1080S	UNIT
Typical thermal resistance	$R_{\theta JC}$	2.2	5.5	2.2	2.2	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	VT1080S-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VFT1080S-E3/4W	1.73	4W	50/tube	Tube
TO-263AB	VBT1080S-E3/4W	1.36	4W	50/tube	Tube
TO-263AB	VBT1080S-E3/8W	1.36	8W	800/reel	Tape and reel
TO-262AA	VIT1080S-E3/4W	1.43	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

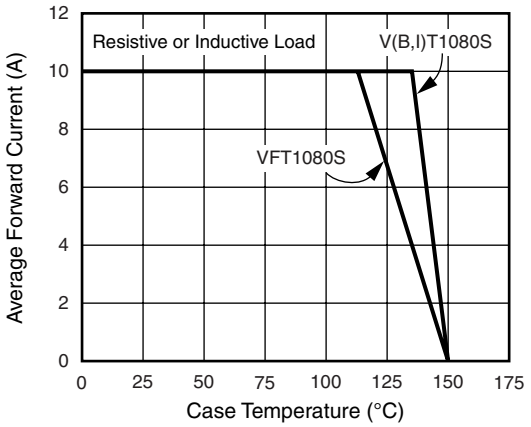


Fig. 1 - Maximum Forward Current Derating Curve

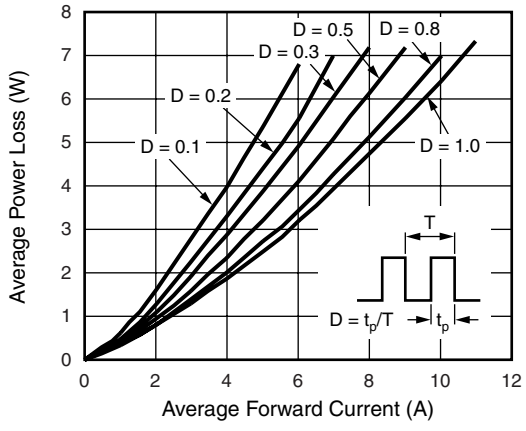


Fig. 2 - Forward Power Loss Characteristics

For technical questions within your region, please contact one of the following:
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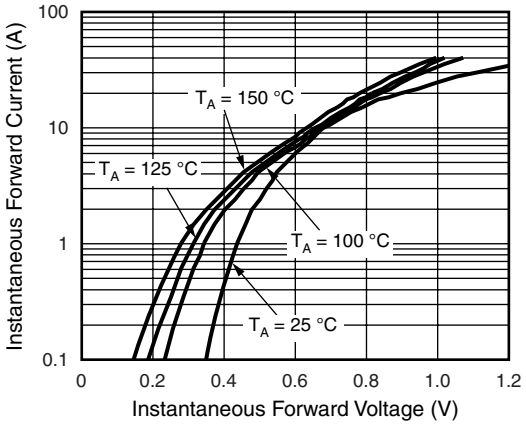


Fig. 3 - Typical Instantaneous Forward Characteristics

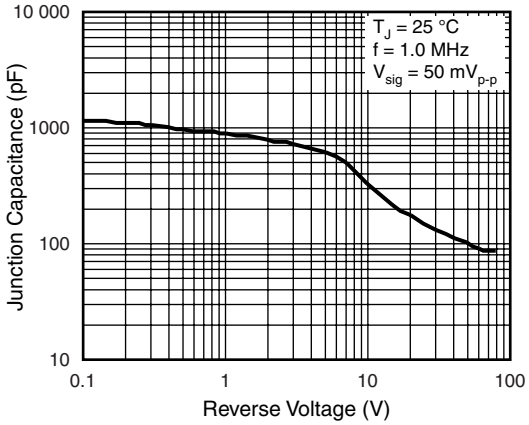


Fig. 5 - Typical Junction Capacitance

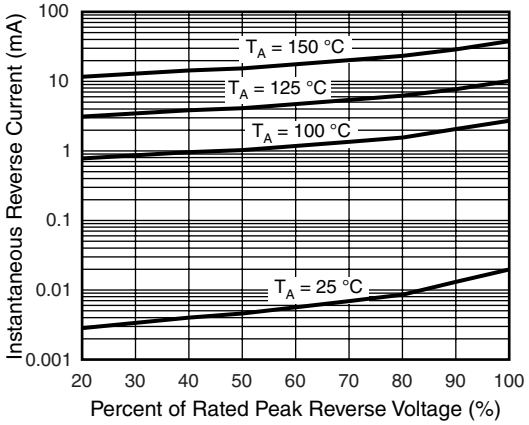


Fig. 4 - Typical Reverse Characteristics

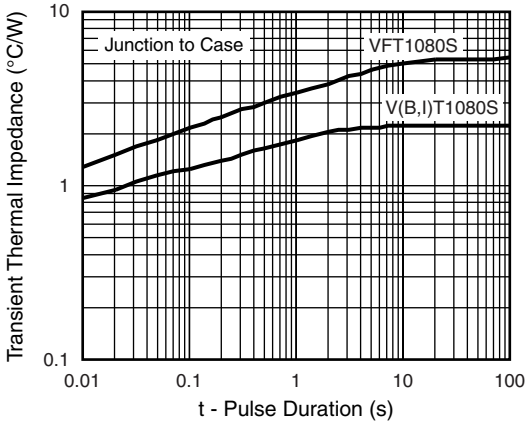
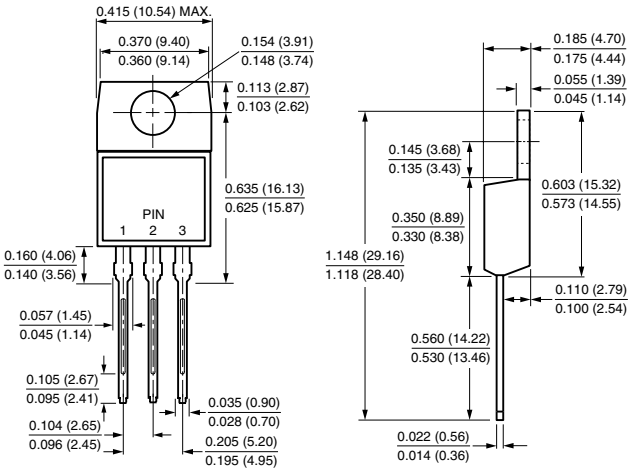


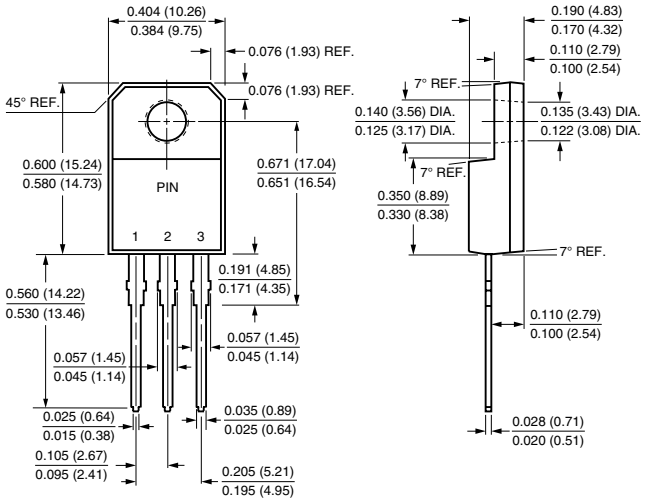
Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

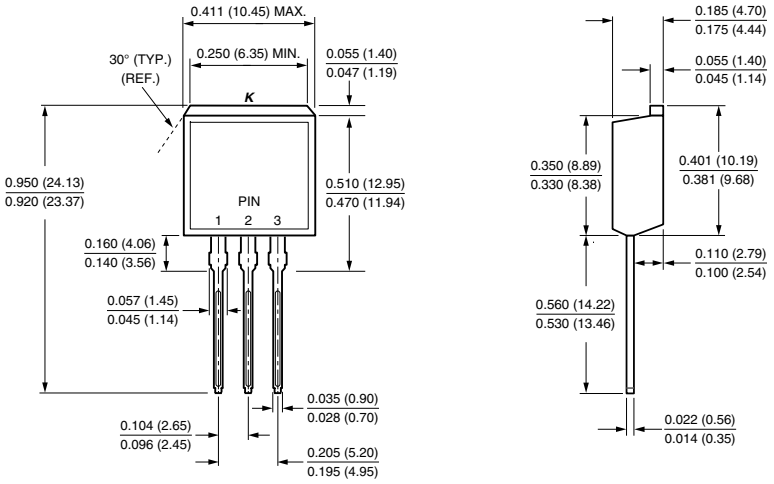
TO-220AB



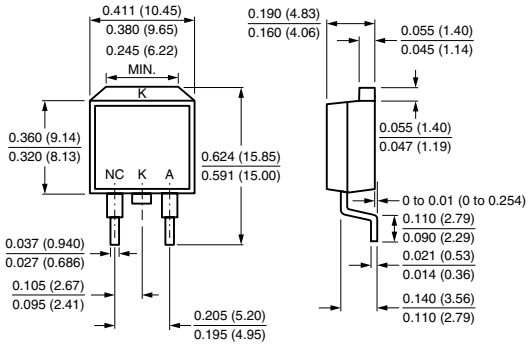
ITO-220AB



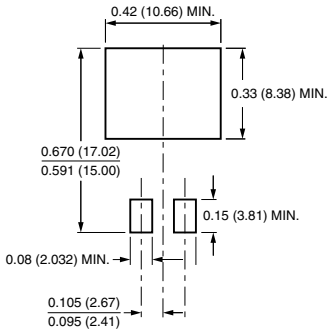
TO-262AA



TO-263AB



Mounting Pad Layout



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